TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOS V-H)

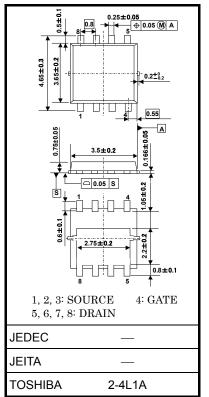
TPCM8004-H

High-Efficiency DC-DC Converter Applications Notebook PC Applications Portable Equipment Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: Q_{SW} = 5.0 nC (typ.)
- Low drain-source ON-resistance: $RDS(ON) = 7.3 m\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 60 \text{ S} (typ.)$
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- Enhancement mode: V_{th} = 1.5 to 2.5 V (V_{DS} = 10 V, I_D = 1 mA)

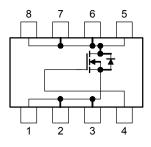
Absolute Maximum Ratings (Ta = 25°C)

Characte	ristic	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	30	V
Drain-gate voltage (R	l _{GS} = 20 kΩ)	V _{DGR}	30	V
Gate-source voltage		V _{GSS}	±20	V
Drain current	DC (Note 1)	۱ _D	24	А
Drain current	Pulsed (Note 1)	I _{DP}	72	~
Drain power dissipati	on (Tc=25°C)	PD	30	W
Drain power dissipati	on (t = 10 s) (Note 2a)	PD	2.3	W
Drain power dissipation (t = 10 s) (Note 2b)		PD	1.0	W
Single-pulse avalanc	ne energy (Note 3)	E _{AS}	75	mJ
Avalanche current		I _{AR}	24	А
Repetitive avalanche (To	energy c = 25°C) (Note 4)	E _{AR}	3.0	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature	range	T _{stg}	-55 to 150	°C



Weight: 0.028 g (typ.)

Circuit Configuration



Note: For Notes 1 to 4, refer to the next page.

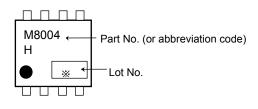
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

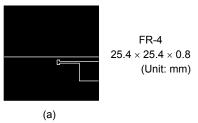
Thermal Characteristics

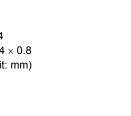
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R _{th (ch-c)}	4.17	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R _{th (ch-a)}	55	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

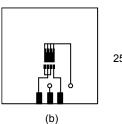
Marking (Note 5)



- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: (a) Device mounted on a glass-epoxy board (a)







FR-4 25.4 × 25.4 × 0.8 (Unit: mm)

(b) Device mounted on a glass-epoxy board (b)

- Note 3: $V_{DD} = 24 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 100 μ H, R_G = 25 Ω , I_{AR} = 24 A
- Note 4: Repetitive rating: pulse width limited by maximum channel temperature
- Note 5: * Weekly code: (Three digits)



Week of manufacture (01 for the first week of the year, continuing up to 52 or 53) Year of manufacture (The last digit of the year)

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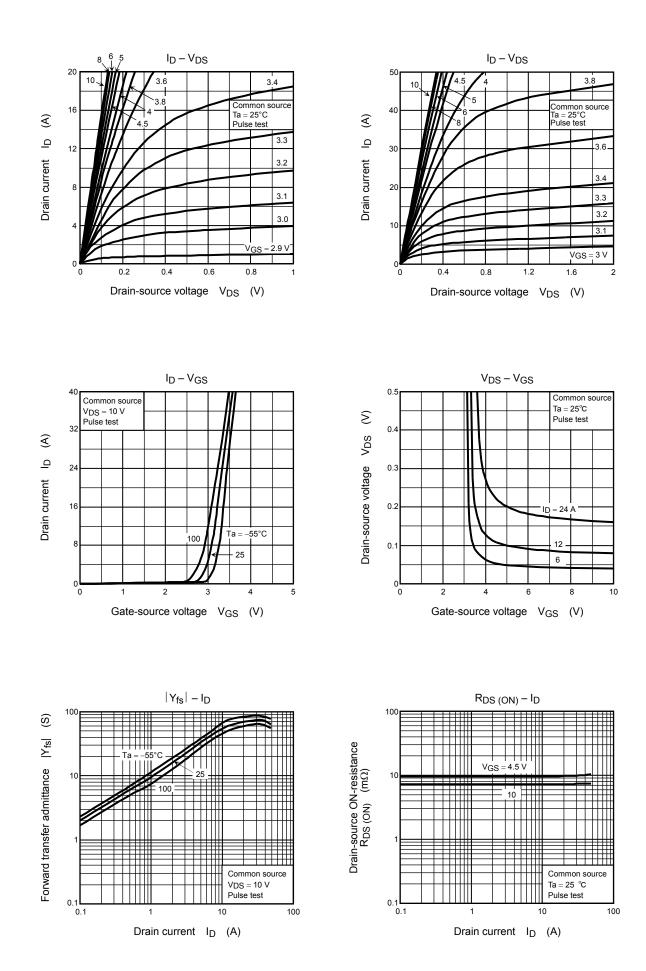
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_		±100	nA
Drain cutoff curre	nt	I _{DSS}	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		10	μA
Dunin anguna kanalalawa walkana		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30		_	v
Drain-source brea	ain-source breakdown voltage		$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	15	_	_	
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	1.5	_	2.5	V
Drain-source ON	rosistanco	Pro (ou)	$V_{GS} = 4.5 \text{ V}, I_D = 12 \text{ A}$	_	9.6	13.4	
Drain-source ON	resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 12 \text{ A}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	mΩ		
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 12 \text{ A}$	30	60	_	S
Input capacitance	9	C _{iss}		_	1433	2150	pF
Reverse transfer	capacitance	C _{rss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz		83	125	
Output capacitance		C _{oss}	-	_	303		
Gate resistance			$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 5 \text{ MHz}$	_	1.0	1.5	Ω
Quitables time	Rise time	tr	$V_{GS} \stackrel{10}{}_{0}V \qquad I_{D} = 12 A$	_	2.8	_	. ns
	Turn-on time	t _{on}		_	9.3	_	
Switching time	Fall time	t _f		_	3.4	_	
	Turn-off time	t _{off}	$V_{DD} \approx 15 V$ Duty $\leq 1\%$, t _w = 10 µs	_	21	_	
Total gate charge	Total gate charge		$V_{DD} \approx 24 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 24 \text{ A}$	_	21		
(gate-source plus	s gate-drain)	Qg	$V_{DD} \approx 24$ V, $V_{GS} = 5$ V, $I_D = 24$ A			_	
Gate-source charge 1		Q _{gs1}	V _{DD} ≈ 24 V, V _{GS} = 10 V, I _D = 24 A	_	4.7		nC
Gate-drain ("Miller") charge		Q _{gd}		_	3.0	—	-
Gate switch charge		Q _{SW}	1		5.0	—	

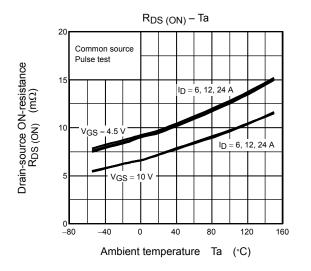
Source-Drain Ratings and Characteristics (Ta = 25°C)

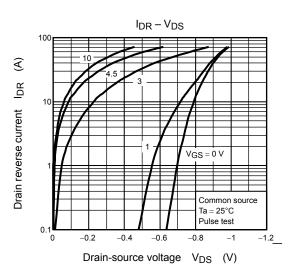
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I _{DRP}	—	_	_	72	А
Forward voltage (diode)			V _{DSF}	$I_{DR} = 24$ A, $V_{GS} = 0$ V		_	-1.2	V

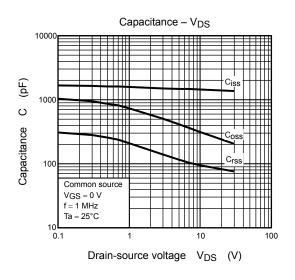
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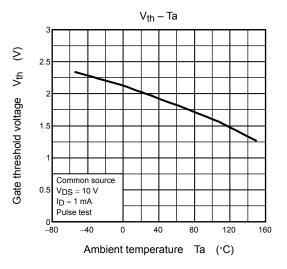


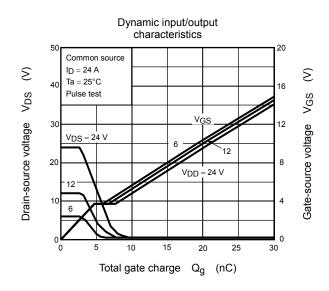
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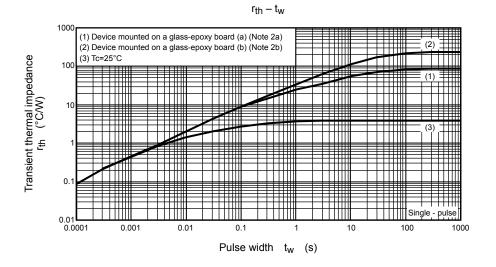




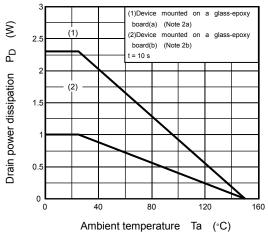


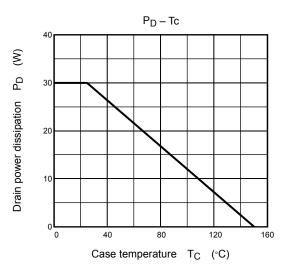


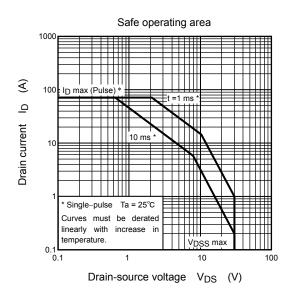












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